53272 POWER MOSFET OPTOCOUPLER

± 90V - 2.0A



Features:

- Performance over –55°C to +125°C
- Compact Solid State Bi-directional Switch
- AC/DC Power Switching
- Maximum Average Current

AC/DC: 1.0 A ⁽¹⁾ DC only: 2.0 A ⁽¹⁾

- Optically Coupled
- Input/Output Isolation Tested to 1000 VDC
- High Level of Transient Immunity
- 3 A Output Surge Current
- Shock and Vibration Resistant
- MIL-PRF-38534
- Electrically Similar to the 53124

Applications:

- Satellite/Space systems
- Military/High Reliability Systems
- Standard 28 VDC and 48 VDC Load Driver
- Standard 24 VAC Load Driver
- Aircraft Controls
- AC/DC Electromechanical and Solid State Relay Replacement
- I/O Modules
- Switching Heaters

DESCRIPTION

The 53272 is a single channel power MOSFET optocoupler expanding upon the electrical performance of Mii P/N 53124 with reduced $R_{DS(ON)}$ and increased current capability.

Performance is specified over the full military temperature range. Functionally, the device operates as a single-pole, normally open (1 Form A) solid-state relay. The device is actuated by an input current, which can be supplied from standard logic types such as open-collector TTL. The input current biases a light emitting diode that is optically coupled to an integrated photovoltaic diode array. The photovoltaic array powers control circuitry that operates the output MOSFETs. Optimum switching of either AC or DC loads is provided by a configurable output. For AC loads, Connection A in Figure 1 must be used. Connection A will also switch DC loads but Connection B, in Figure 1, provides DC-only operation with the advantages of substantial reduction in on-resistance and twice the output current capability as that obtained with Connection A.

ABSOLUTE MAXIMUM RATINGS:

Operating Ambient Temperature - T_A	-65°C to +150°C -55°C to +125°C +150°C +145°C (2)
	+260°C
	(1.6 mm below seating plane)
Average Input Current - I _F	20 mA
Peak Repetitive Input Current - I _{Fpk}	40 mA
5 10 1 10 11	(Pulse width < 100 ms; duty cycle < 50%)
Peak Surge Input Current - I _{Fpk} surge	100 mA
Davida lagrativata and M	(Pulse width < 0.2 ms; duty cycle < 0.1%)
	5 V
Average Output Current	(1)
Connection A - I _o	
	2.0 A ⁽¹⁾
Average Output Current, derated per Figure 3	
	0.8 A
	1.6 A
Single Shot Output Current - Figure 4	
	4 A
Connection B - I _{Opk} surge (Pulse width < 10 ms)	8 A
Output Voltage	
Connection A - V _O	_90 V to +90 V
Connection B - V _O	0 V to +90 V
Average Output Power Dissipation - Figure 5	

RECOMMENDED OPERATING CONDITIONS:

Parameter	Symbol	Min.	Max.	Units
Input Current (ON)	I _{F (ON)}	5	20	mA
Input Voltage (OFF)	V _{F (OFF)}	0	0.6	VDC
Operating Temperature	T _A	-55	+125	°C

ELECTRICAL SPECIFICATIONS $T_A = -55^{\circ}C$ to $+125^{\circ}C$, unless otherwise specified.

Parameter	Symbol	Min.	Тур.*	Max.	Unit s	Test Conditions	Notes
Output Withstand Voltage	V _{O(OFF)}	90	110		V	$V_F = 0.6 \text{ V}$ $I_O = 10 \mu\text{A}$	
Output On-Resistance (Connection A)	D		.40	.68	Ω	I_F = 10 mA I_O = 1 A (pulse duration \leq 30 ms)	4,
Output On-Resistance (Connection B)	$R_{(ON)}$		0.10	0.18	Ω	I_F = 10 mA I_O = 1 A (pulse duration \leq 30 ms)	Figure 1
Output Leakage Current	I _{O (OFF)}		10 ⁻⁴	10	μΑ	$V_F = 0.6 V$ $V_O = 90 V$	
Input Forward Voltage	V_{F}	1.0	1.7	2.1	V	I _F = 10 mA	
Input Reverse Breakdown Voltage	V_{R}	5			V	I _F = 10 μA	
Input-Output Insulation	I _{I-O}			1	μА	RH \leq 45%, t = 5 s V _{I-O} = 1000 VDC T _A = 25°C	5, 6
Turn-On Time	t _{on}		2.0	8	ms	I_F = 10 mA V_{DD} = 28 V I_O = 800 mA	Figure 6
Turn-Off time	t_{OFF}			0.3	ms	$I_F = 10 \text{ mA}$ $V_{DD} = 28 \text{ V}$ $I_O = 800 \text{ mA}$	Figure 6

^{*} All typical values are at T_A = 25°C, $I_{F(ON)}$ = 10 mA, $V_{F(OFF)}$ = 0.6 V unless otherwise specified.

TYPICAL CHARACTERISTICS

All typical values are at $T_A = 25$ °C, $I_{F(ON)} = 10$ mA, $V_{F(OFF)} = 0.6$ V unless otherwise specified.

Parameter	Symbol	Test Conditions	Typical Value	Units	Notes
Output Off-Capacitance	C _{O (OFF)}	V _O = 28 V f = 1 MHz	145	pF	
Output Offset Voltage	Vos	$I_F = 10 \text{ mA}$ $I_O = 0 \text{ mA}$	2	μV	7
Input Diode Temperature Coefficient	$\Delta V_F / \Delta T_A$	I _F = 10 mA	-1.4	mV/°C	
Input Capacitance	C _{IN}	$V_F = 0 V$ f = 1 MHz	20	pF	8
Input-Output Capacitance	C _{I-O}	V _{I-O} = 0 V f = 1 MHz	1.5	pF	5
Input-Output Resistance	R _{I-O}	$V_{I-O} = 500 \text{ V}$ t = 60 s	10 ¹³	Ω	5

Notes:

- Maximum average current rating where the case temperature (T_C) is maintained below 120°C.
- 2. Maximum junction to case thermal resistance for the device is 15°C/W, where case temperature (T_C) is measured at the center of the package bottom.
- 3. For rating, see Figure 5. The output power P_D rating curve is obtained when the part is handling the maximum average output current I_D as shown in Figure 3.
- 4. During the pulsed R_{ON} measurement (I_O duration < 30 ms), ambient (I_A) and case temperature (I_C) are equal.
- 5. Pins 2 through 3 shorted together and pins 5 through 8 shorted together.
- 6. This is a momentary withstand test, not an operating condition.
- 7. V_{OS} is a function of I_F and is defined between pins 5 and 8, with pin 5 as the reference. V_{OS} must be measured in a stable ambient (free of temperature gradients).
- 8. Zero-bias capacitance measured between the LED anode and cathode.

CAUTION:

Care should be taken not to exceed the maximum output power dissipation, maximum case temperature, and maximum junction temperature when repetitively switching loads.

Case Outlines	P, X and Y		
Terminal number	Terminal symbol		
	Connection A Connection		
	(AC or DC load)	(DC load only)	
1	NC	NC	
2	V _{F+}	V _{F+}	
3	V _{F-}	V _{F-}	
4	NC	NC	
5	V _{O-}	V _{O+}	
6	NC	NC	
7	NC	N _{O-}	
8	V _{O+}	N _{O+}	

NC = No Connection

CONNECTION A AC/DC CONNECTION

CONNECTION B DC CONNECTION

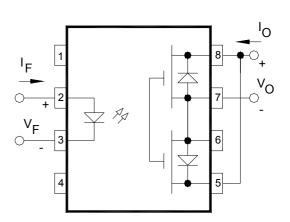
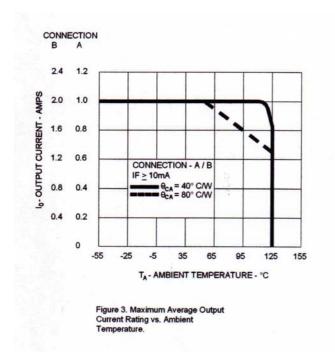


Figure 1 - Terminal Connections

INPUT	OUTPUT
OFF	OFF
ON	ON

Figure 2 - Truth Table



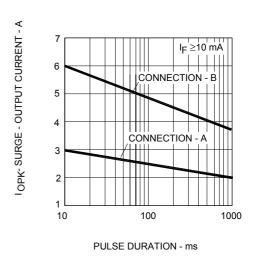
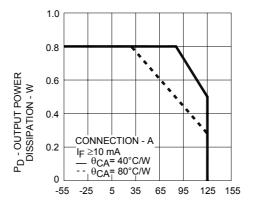
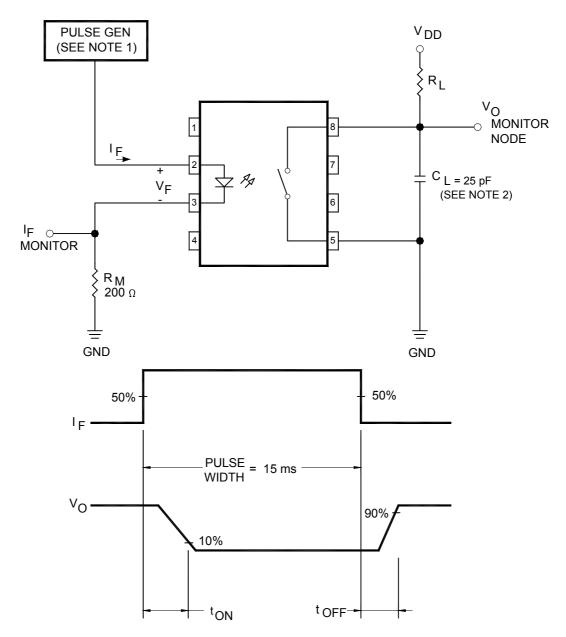


Figure 4. Single Shot (non-repetitive) Output Current vs. Pulse Duration.



T_A - AMBIENT TEMPERATURE - °C

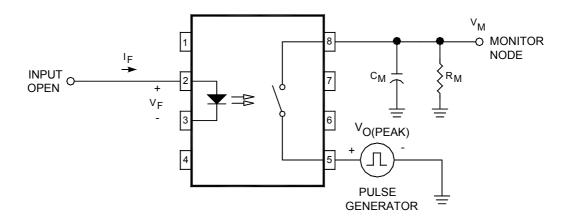
Figure 5. Output Power Rating vs. Ambient Temperature.

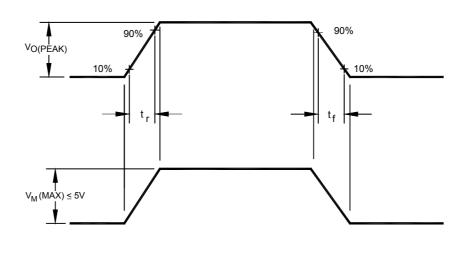


NOTES:

- 1. PULSE GENERATOR HAS THE FOLLOWING CHARACTERISTICS: OUTPUT IMPEDANCE = 50 Ω AND $t_{\rm f}$ = $t_{\rm f}$ = 5.0 ns.
- 2. LOAD CAPACITANCE (C1) INCLUDES PROBE AND JIG CAPACITANCE.

Figure 6. Switching Test Circuit and Waveform.





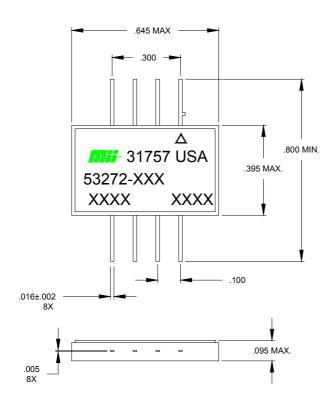
$$\frac{d V_O}{d_f} = \frac{(0.8) V_O (PEAK)}{t_f} OR \frac{(0.8) V_O (PEAK)}{t_f}$$

OVERSHOOT ON V_{O} (PEAK) IS TO BE $\leq 10\%$

NOTES:

- 1. C_M INCLUDES PROBE AND FIXTURE CAPACITANCE. 2. R_M INCLUDES PROBE AND FIXTURE RESISTANCE.

Package Dimensions



Ordering Information

53272E	Engineering Unit Non-Rad Version
53272-102	ETU Rad Version No Screening
53272-108	Rad Version Screened to H + PIND
53272-XXX	TBD